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N-Channel 80 V (D-S) 175 °C MOSFET

DESCRIPTION

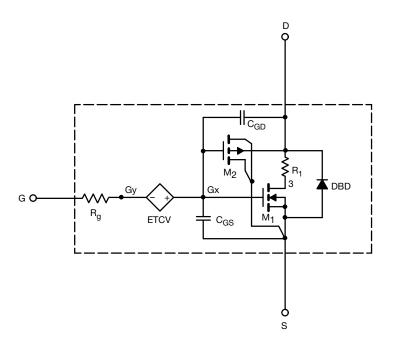
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-channel vertical DMOS
- Macro model (subcircuit model)
- Level 3 MOS
- · Apply for both linear and switching application
- Accurate over -55 °C to +125 °C temperature range
- · Model the gate charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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| SPECIFICATIONS (T _J = 25 °C, unless otherwise noted) | | | | | |
|--|---------------------|---|----------------|------------------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS | SIMULATED DATA | MEASURED DATA | UNIT |
| Static | | | | | |
| Gate-source threshold voltage | V _{GS(th)} | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | 2 | 2 | V |
| Drain-source on-state resistance ^a | R _{DS(on)} | $V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$ | 0.0058 | 0.0058 | Ω |
| | | $V_{GS} = 4.5 \text{ V}, I_D = 8 \text{ A}$ | 0.0080 | 0.0077 | |
| Forward transconductance ^a | 9 _{fs} | $V_{DS} = 15 \text{ V}, I_D = 10 \text{ A}$ | 54 | 78 | S |
| Diode forward voltage | V_{SD} | I _S = 10 A | 0.80 | 0.80 | V |
| Dynamic ^b | | | | | |
| Input capacitance | C _{iss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | 2760 | 2800 | pF |
| Output capacitance | Coss | | 1400 | 1400 | |
| Reverse transfer capacitance | C _{rss} | | 73 | 73 | |
| Total gate charge | Qg | | 39 | 40 | |
| Gate-source charge | Q_{gs} | $V_{DS} = 40 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}$ | 8 | 8 | nC |
| Gate-drain charge | Q_{gd} | | 6 | 6 | |

Notes

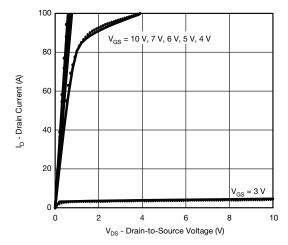
- a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing

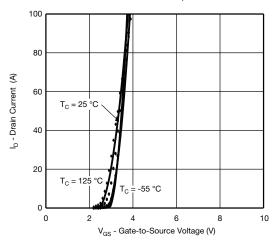


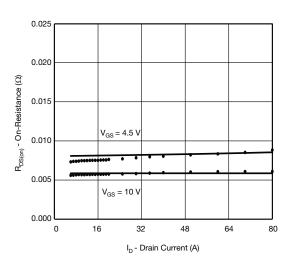
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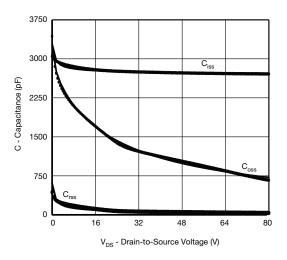
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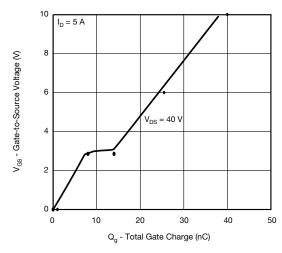
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25~^{\circ}C$, unless otherwise noted)

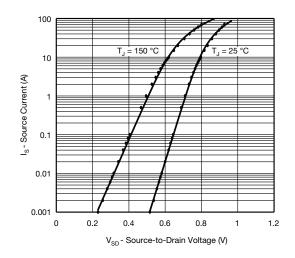












Note

 Dots and squares represent measured data Copyright: Vishay Intertechnology, Inc.



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